



S E M I C O N D U C T O R

# LS12 THRU LS120

## SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts

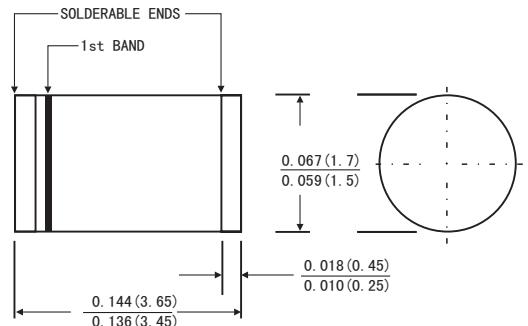
Forward Current - 1.0Ampere

### FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- For surface mount applications
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, Low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 260°C/10 seconds at terminals
- Component in accordance to RoHS 2011/65/EU



### MiniMELF(DO-213AA)



### MECHANICAL DATA

- Case: JEDEC Mini MELF(DO-213AA) molded plastic body
- Terminals: Solder Plated, solderable per MIL-STD-750, method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any

Dimensions in inches and (millimeters)

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified, Single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%.)

	Symbols	LS 12	LS 13	LS 14	LS 16	LS 110	LS 115	LS 120	Volts
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	60	100	150	200	Volts
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	42	71	105	140	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	60	100	150	200	Volts
Maximum average forward rectified current (See Fig. 1)	I <sub>(AV)</sub>	1.0						Amp	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I <sub>FSM</sub>	40.0						Amps	
Maximum instantaneous forward voltage at 1.0 A (note 1)	V <sub>F</sub>	0.55		0.75	0.85	0.90	0.95	Volts	
Maximum instantaneous reverse current at rated DC blocking voltage (Note 1)	T <sub>A</sub> =25°C	100				20		μA	
	T <sub>A</sub> =100°C	5.0				-		mA	
	T <sub>A</sub> =125°C	-				3.0			
Typical thermal resistance (Note 2)	R <sub>θJA</sub> R <sub>θJL</sub>	75.0 30.0						°C/W	
Operating junction temperature range	T <sub>J</sub>	-65 to +150						°C	
Storage temperature range	T <sub>STG</sub>	-65 to +150						°C	

Notes: 1. Pulse test: 300 μs pulse width, 1% duty cycle

2. P.C.B. mounted with 0.2 X 0.2" (5.0 X 5.0mm) copper pad areas

# RATINGS AND CHARACTERISTIC CURVES LS12 THRU LS120

FIG.1-FORWARD CURRENT DERATING CURVE

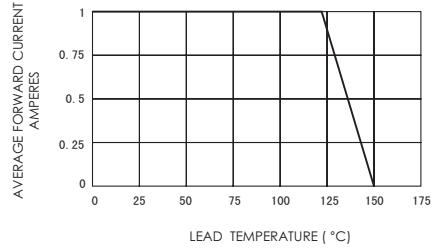


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

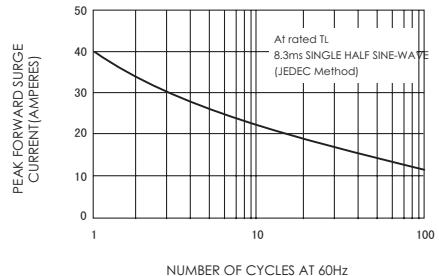


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

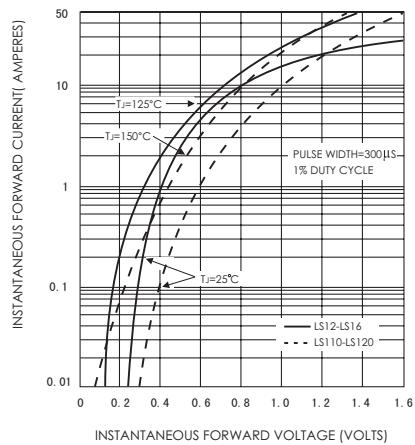


FIG.4-TYPICAL REVERSE CHARACTERISTICS

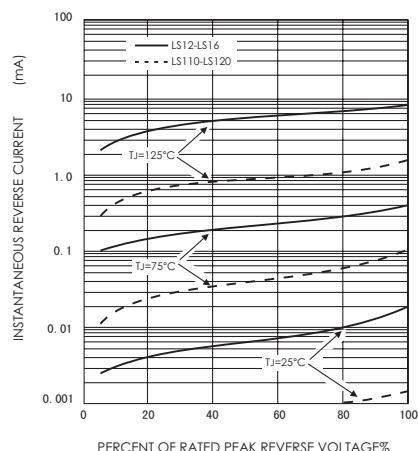


FIG.5-TYPICAL JUNCTION CAPACITANCE

